

NCE07TD60BD

600V, 7A, Trench FS II Fast IGBT

General Description:

Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 600V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Air Condition
- Inverters
- Motor drives

Package Marking and Ordering Information

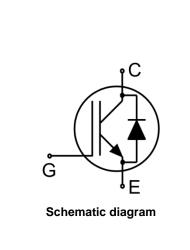
Device	Device Package	Device Marking		
NCE07TD60BD	TO-263	NCE07TD60BD		



TO-263

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Value	Units	
VCES	Collector-Emitter Voltage	600	V	
V _{GES}	Gate- Emitter Voltage	±30	V	
1	Collector Current	14	А	
lc	Collector Current @T _C = 100 °C	7	А	
I _{Cplus}	Pulsed Collector Current, tp limited by Tjmax	21	A	
-	turn off safe operating area, V _{CE} =600V, T _J =150°C	21	А	
l _F	Diode Continuous Forward Current @T _C = 100 °C	7	А	
Іғм	Diode Maximum Forward Current	21	А	
5	Power Dissipation @ T _C = 25°C	73	W	
PD	Power Dissipation @T _c = 100 °C	36.5	W	
T_{J},T_{stg}	Operating Junction and Storage Temperature Range	-55 to +175	°C	
T∟	Maximum Temperature for Soldering	260	°C	
t _{sc}	Short circuit withstand time V_{GE} =15V, $V_{CC} \le 400V$, Allowed number of short circuits<1000Time between short circuits: \ge 1.0s, $T_j \le$ 150°C	5	us	





NCE07TD60BD

Thermal Characteristic

Symbol	Parameter	Value	Units
Rejc	Thermal Resistance, Junction to case for IGBT	2.05	°C/W
Rejc	Thermal Resistance, Junction to case for Diode	2.50	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	62	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Questo	Denometer	Test Conditions		Value			11
Symbol	Parameter			Min.	Тур.	Max.	Units
Static Chara	cteristics			L			
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V	,I _{CE} =1mA	600			V
ICES	Collector-Emitter Leakage Current	V _{GE} =0V,V _{CE} =600V				4	uA
IGES(F)	Gate to Emitter Forward Leakage	V _{GE} =+30V,V _{CE} =0V				100	nA
I _{GES(R)}	Gate to Source Reverse Leakage	V _{GE} =-30	V,Vce =0V			100	nA
V _{CE(sat)}	Collector-Emitter Saturation Voltage	Ic=5A V _{GE} =15V	Tj=25°C Tj=100°C		1.7 1.9	1.9	V V
V _{GE(th)}	Gate Threshold Voltage	Ic=1mA,VcE=VGE		4.0	5.0	6.0	V
Dynamic Cha	aracteristics						
Cies	Input Capacitance	V _{CE} =25V, V _{GE} =0V, f=1MHz			675		pF
Coes	Output Capacitance				22		
Cres	Reverse Transfer Capacitance				13		
Qg	Total Gate Charge	Vcc=480V, Ic=7A, V _{GE} =15V			28		nC
Qge	Gate to Emitter Charge				8		
Q _{gc}	Gate to Collector Charge				13		
I _{C(SC)}	Short circuit collector current Max.1000 short circuits Time between short circuits: \geq 1.0s	V _{GE} =15V,V _{CC} ≪400V, t _{SC} ≪5us,Tj≪150°C			34		A
Switching Cl	haracteristics						
t _{d(ON)}	Turn-on Delay Time				20		
tr	Rise Time				15		- ns
$t_{\text{d}(\text{OFF})}$	Turn-Off Delay Time	V _{CC} =400V,Ic=7A, V _{GE} =0/15V, R _g =5Ω			73		115
t _f	Fall Time				18		
Eon	Turn-On Switching Loss	Inducti	ve Load		0.21		
E _{off}	Turn-Off Switching Loss				0.10		mJ
Ets	Total Switching Loss				0.31		

Electrical Characteristics of the Diode(Tc= 25°C unless otherwise specified):

Symbol	Parameter	Toot Conditions	Rating			Units
Symbol		Test Conditions	Min.	Тур.	Max.	Units
Vfm	Diode Forward Voltage	I _F =7A		1.5	1.7	V
Trr	Reverse Recovery Time			230		ns
IRRM	Diode Peak Reverse Recovery Current	I⊧=7A, di/dt=200A/us		3.5		А
Qrr	Reverse Recovery Charge			0.44		uC
Pulse width $t_{tp} \leq 380 \mu s, \delta \leq 2\%$						

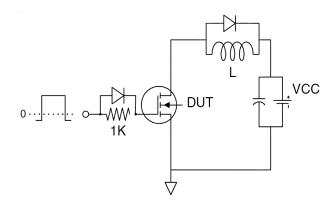




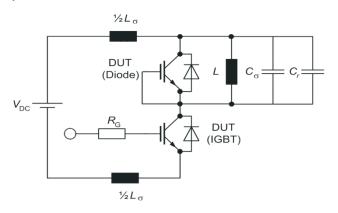
NCE07TD60BD

Test Circuit

1) Gate Charge Test Circuit

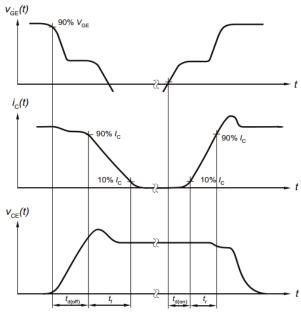


2) Switch Time Test Circuit

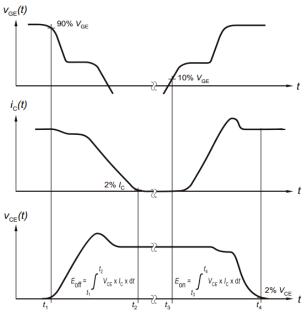


Switching characteristics

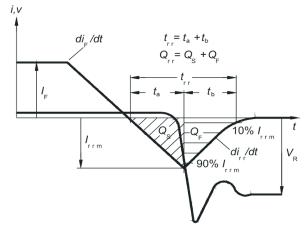
1) Definition of switching times



2) Definition of switching losses

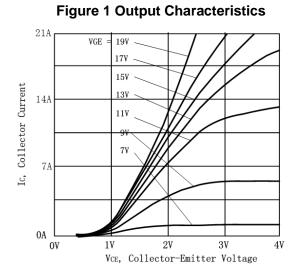


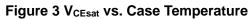
3) Definition of diode switching characteristics

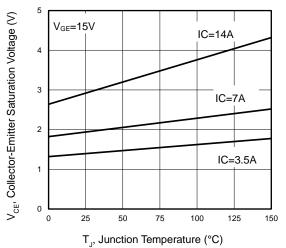




Typical Electrical and Thermal Characteristics









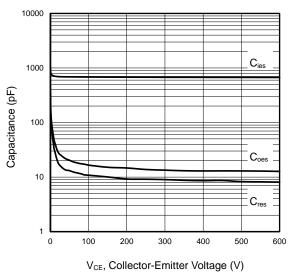


Figure 2 Transfer Characteristics

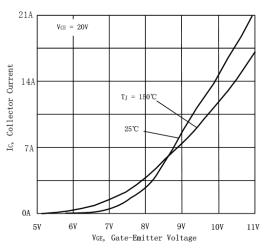
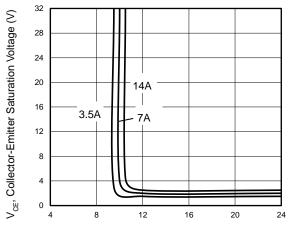
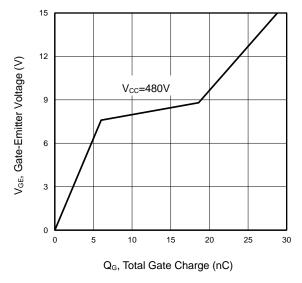


Figure 4 Saturation Voltage vs. V_{GE}



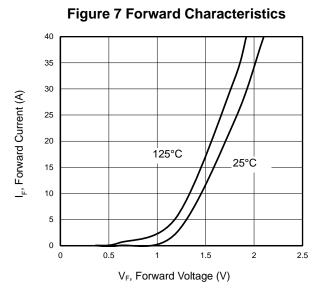
V_{GE}, Gate-Emitter Voltage (V)

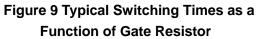
Figure 6 Gate charge waveform

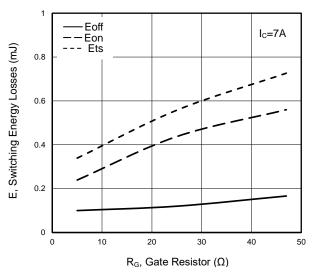




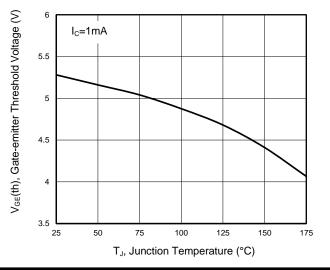
Typical Electrical and Thermal Characteristics











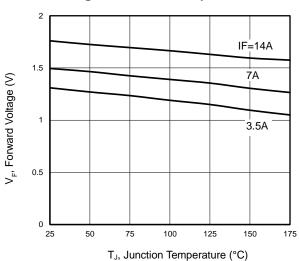


Figure 10 Typical Switching Times as a **Function of Junction Temperature**

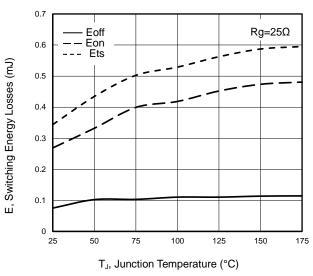


Figure 12 Typical Collector-emitter Saturation Voltage as a function of Collector Current

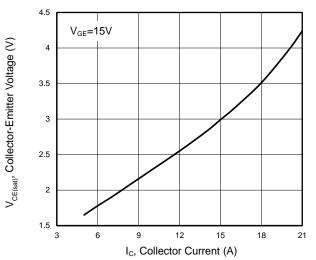


Figure 8 V_F vs. Temperature



Typical Electrical and Thermal Characteristics

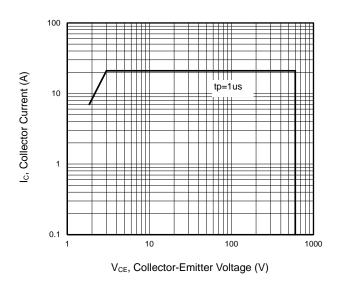
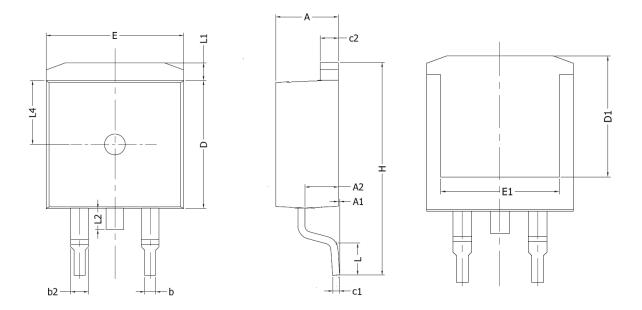


Figure 13 Forward Bias Safe Operating Area



TO-263-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	4.40	4.60	0.17	0.18	
A1	0.00	0.25	0.00	0.01	
A2	2.20	2.60	0.09	0.10	
b	0.76	0.89	0.03	0.04	
b2	1.23	1.37	0.05	0.05	
С	0.47	0.60	0.02	0.02	
c1	0.46	0.56	0.02	0.02	
c2	1.25	1.35	0.05	0.05	
D	0.91	0.93	0.04	0.04	
D1	8.00	-	0.31	-	
E	9.80	10.00	0.39	0.39	
E1	7.80	-	0.31	-	
е	2.5	4BSC	0.10BSC		
н	14.90	15.70	0.59	0.62	
L	2.00	2.60	0.08	0.10	
L1	1.17	1.40	0.05	0.06	
L2	-	1.75	-	0.07	
L4	4.6	0REF	0.18REF		



PbFreeProduct NCE07TD60BD

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